## AMENDMENTS TO THE CLAIMS

(Currently amended) An imaging system comprising:

a radiation source directing radiation along a propagation axis;

a detector assembly positioned to receive the radiation, the detector assembly including a plurality of <u>substantially planar</u> sheets oriented to extend substantially along the propagation axis and spaced transversely across the axis to define a plurality of axially extending detector volumes; and

detection means detecting negatively and positively charged high-energetic particles liberated into the detector volumes to provide for substantially independent signals, wherein the detection means includes amorphous selenium.

- 2. (Cancel)
- 3. (Currently amended) An imaging system comprising:
  - a radiation source directing megavoltage radiation along a propagation axis;

a detector assembly positioned to receive the radiation, the detector assembly including a plurality of <u>substantially planar</u> sheets oriented to extend substantially along the propagation axis and spaced transversely across the axis to define a plurality of axially extending detector volumes, the sheets receiving the megavoltage radiation longitudinally; and

detection means detecting negatively and positively charged high-energetic particles liberated into the detector volumes to provide for substantially independent signals, wherein the detection means includes amorphous selenium.

4. (Withdrawn) A method of fabricating a megavoltage radiation detector, the method comprising the steps of:

depositing a plurality of readout electrodes on at least one surface of a substrate; depositing an amorphous selenium layer on at least one surface of the readout electrodes; and

depositing a high voltage electrode layer on at least one surface of the amorphous selenium layer.

5. (Previously presented) The imaging system of claim 1 wherein the detector assembly includes a housing that supports a high voltage bus bar operable to connect to a high voltage source and wherein each sheet is connectable to the high voltage bus bar.

- 6. (Previously presented) The imaging system of claim 5 wherein a surface of the detection means is in contact with the sheet and receives an electrical charge.
- 7. (Cancel)
- 8. (Previously presented) The imaging system of claim 1 wherein the detector assembly includes a dielectric element having alignment means for positioning the sheets within the detector assembly.
- 9. (Previously presented) The imaging system of claim 8 wherein the radiation diverges from the radiation source and wherein the dielectric element is curved to orient the plurality of sheets corresponding to the divergence of the radiation.
- 10. (Previously presented) The imaging system of claim 1 wherein the radiation source directs megavoltage radiation along the propagation axis.
- 11. (Previously presented) The imaging system of claim 1 wherein the detection means includes a plurality of layers.
- 12. (Previously presented) The imaging system of claim 11 wherein the plurality of layers includes a first layer comprised of the amorphous selenium, a readout electrode layer, and a substrate layer.
- 13. (Previously presented) The imaging system of claim 12 wherein the substrate layer comprises an insulation material.
- 14. (Previously presented) The imaging system of claim 13 wherein the insulation material comprises glass.
- 15. (Previously presented) The imaging system of claim 3 wherein the detector assembly includes a housing that supports a high voltage bus bar operable to connect to a high voltage source and wherein each sheet is connectable to the high voltage bus bar.

- 16. (Previously presented) The imaging system of claim 15 wherein a surface of the detection means is in contact with the sheet and receives an electrical charge.
- 17. (Cancel)
- 18. (Previously presented) The imaging system of claim 3 wherein the detection means includes a plurality of layers.
- 19. (Previously presented) The imaging system of claim 18 wherein the plurality of layers includes a first layer comprised of the amorphous selenium, a readout electrode layer, and a substrate layer.
- 20. (Previously presented) The imaging system of claim 10 wherein the substrate layer comprises an insulation material.
- 21. (Previously presented) The imaging system of claim 20 wherein the insulation material comprises glass.